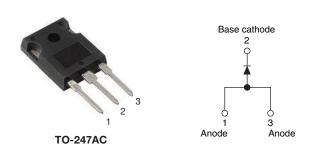


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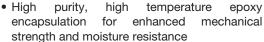
High Performance Schottky Rectifier, 65 A

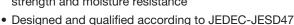


PRODUCT SUMMARY				
Package	TO-247AC			
I _{F(AV)}	65 A			
V _R	15 V			
V _F at I _F	0.46 V			
I _{RM} max.	870 mA at 100 °C			
T _J max.	125 °C			
Diode variation	Single die			
E _{AS}	9 mJ			

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Single diode configuration
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability





 Material categorization: For definitions of compliance please see www.vishav.com/doc?99912





DESCRIPTION

The VS-65PQ015... Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	65	А			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	1500	А			
V _F	65 A _{pk} , T _J = 125 °C	0.46	V			
TJ	Range	- 55 to 125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VS-65PQ015PbF	VS-65PQ015-N3	UNITS	
Maximum DC reverse voltage	\/_	T _J = 100 °C	15	15	W	
	V _R	T _J = 125 °C	5	5	V	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 83 °C, r	65			
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500	Α	
non-repetitive surge current		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	400		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4.5 mH		9	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2	А	



VS-65PQ015PbF, VS-65PQ015-N3

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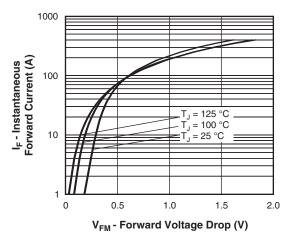
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS	
		65 A	T _{.1} = 25 °C	0.50	V
Forward voltage drop	V _{FM} ⁽¹⁾	130 A	11 = 23 0	0.71	
Forward voltage drop	VFM (')	65 A	T _{.1} = 125 °C	0.46	
		130 A	1J = 125 C	0.76	
	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = 5 V	1.2	А
Reverse leakage current		$T_J = 25 ^{\circ}C$	V Datad V	18	- mA
		T _J = 100 °C	V _R = Rated V _R	870	
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.137	mV
Forward slope resistance	r _t	ıj = ıj maximum	4.9	mΩ	
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		4300	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

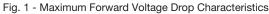
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		- 55 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 55 to 150	C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.8	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.3		
Approximate weight			6	g	
Approximate weight			0.21	oz.	
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm	
maximum		Non-iublicateu tilleaus	12 (10)	(lbf · in)	
Marking device		Case style TO-247AC (JEDEC)	65PC	Q015	







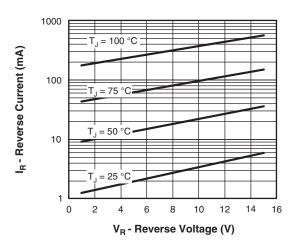


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

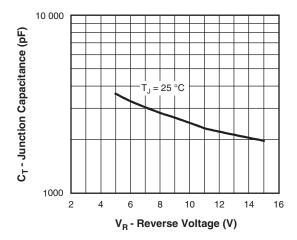


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

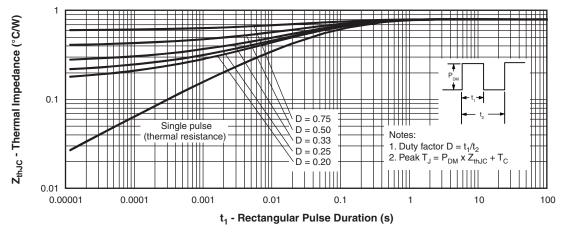


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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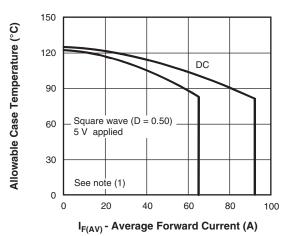


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

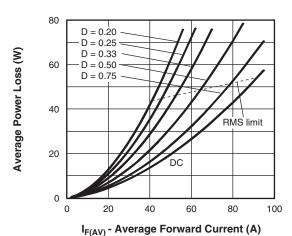


Fig. 6 - Forward Power Loss Characteristics

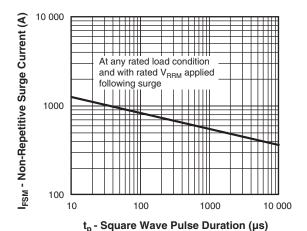


Fig. 7 - Maximum Non-Repetitive Surge Current

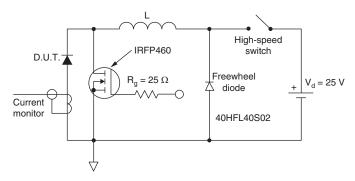


Fig. 8 - Unclamped Inductive Test Circuit

Note

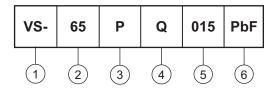
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 5 V

VS-65PQ015PbF, VS-65PQ015-N3

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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (65 = 65 A)
- 3 Package:

P = TO-247

- 4 Schottky "Q" series
- 5 Voltage code (015 = 15 V)
- 6 Environmental digit
 - PbF = Lead (Pb)-free and RoHS compliant
 - -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-65PQ015PbF	25	500	Antistatic plastic tube			
VS-65PQ015-N3	25	500	Antistatic plastic tube			

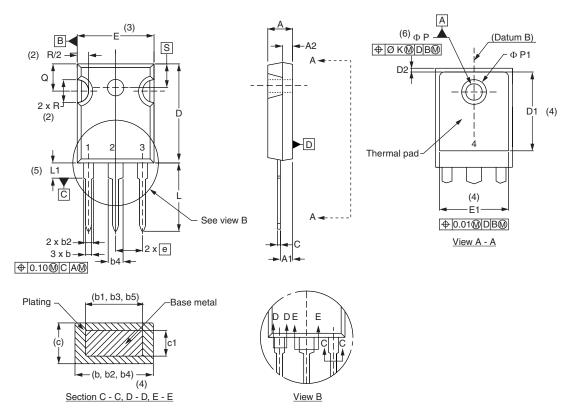
LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95542		
Deut eranding information	TO-247AC modified PbF	www.vishay.com/doc?95226		
Part marking information	TO-247AC modified -N3	www.vishay.com/doc?95007		
SPICE model		www.vishay.com/doc?95306		



Vishay Semiconductors

TO-247AC - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES	
STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.254		0.0)10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	
			.		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$ Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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